

2.4-2.5 GHz Front-End Module with Internally Matched Power Amplifier and SP3T Switch

PRODUCTION DATA SHEET

DESCRIPTION

LX5543 is a WLAN front-end module (FEM) for 802.11b/g/n and other applications in the 2.4-2.5GHz frequency range. LX5543 integrates an advanced InGaP/GaAs Heterojunction Bipolar Transistor (HBT) power amplifier with on chip impedance matching and a Depletion mode pHEMT (D-pHEMT) single-pole triple-throw (SP3T) switch in a single package with 3x3mm footprint. LX5543 provides capability of sharing a single antenna between WLAN and Bluetooth systems through the SP3T switch.

The Tx path of LX5543 features a two-stage monolithic microwave integrated circuit (MMIC) power amplifier with active bias circuitry, on-chip output power detector, and 50Ω input/output matching inside the package. With 3.6V supply voltage and 82mA bias current, the Tx path

LX5543 is a WLAN front-end provides about 25dB power gain, and module (FEM) for 802.11b/g/n and +17dBm linear output power, with other applications in the 2.4-2.5GHz EVM (<3%) for 64QAM/ 54Mbps frequency range. LX5543 integrates OFDM. Both gain and power are an advanced InGaP/GaAs Heteroreadily measured at antenna port, with junction Bipolar Transistor (HBT) the insertion loss of the SP3T switch power amplifier with on chip included.

impedance matching and a Depletion mode pHEMT (D-pHEMT) single-pole triple-throw (SP3T) switch in a single package with 3x3mm footprint. (IP $_{1dB}$) of +25dBm. Bluetooth path of LX5543 provides capability of sharing a single antenna between WLAN and IP $_{1dB}$ of +29dBm.

LX5543 is available in a 16-pin, low profile of 0.55mm, 3x3mm² microlead package (MLPQ-16L). With its high level of functional integration, best-class performance, compact footprint and low profile, LX5543 offers an ideal front-end solution for the ever demanding design requirements of today's highly integrated mobile equipments, including 802.11 b/g/n and Bluetooth applications.

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

KEY FEATURES

- 2.4-2.5GHz 802.11b/g/n Front-End Solution in a Single MLP Package
- SP3T for Sharing Antenna between WLAN and Bluetooth systems
- All RF I/O Matched to 50 Ω
- Single-Supply Voltage 3.0V to 4.2V
- Small Footprint: 3x3mm²
- Low Profile: 0.55mm
- RoHS Compliant & Pb-Free

TX Features:

- Power Gain ~ 25dB*
- Pout ~ +17dBm* for 3% EVM at Antenna
- Current ~145mA at +17dBm*
- Pout ~ +21dBm* for 11b 1Mbps DSSS Mask Compliance
- Quiescent Current ~ 82mA

RX Features:

- Insertion Loss ~ 0.6 dB
- IP_{1dB} ~ +25 dBm

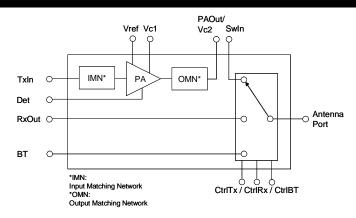
Bluetooth Path:

- Insertion Loss ~ 0.9 dB
- IP_{1dB} ~ +29 dBm
- * Including SP3T switch loss

APPLICATIONS

- IEEE 802.11b/g/n
- Mobile Phone WLAN module

BLOCK DIAGRAM

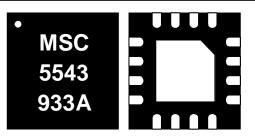




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PRODUCT HIGHLIGHT



PACKAGE ORDER INFO

LU

Plastic MLPQ 16 pin 3x3mm RoHS Compliant /Pb-Free

LX5543LU

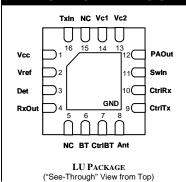
Note: Available in Tape & Reel. Append the letters "TR" to the part number. (i.e. LX5543LU-TR)

ABSOLUTE MAXIMUM RATINGS

DC Supply Voltage, RF off	5V
Collector Current (PA)	500mA
Total Power Dissipation	2W
RF Input Power (TxIn)	+10dBm
RF Input Power (Ant, SwIn, BT)	+25dBm
Maximum Junction Temperature (Tj max)	+150°C
Operation Ambient Temperature	40° C to $+85^{\circ}$ C
Storage Temperature	65°C to $+150$ °C
RoHS/Pb-Free Peak Package Temp. for Solder Reflow	
(40 seconds maximum exposure)	260°C (+0, -5)
-	

Note: Exceeding these ratings could cause damage to the device. All voltages are with respect to Ground. Currents are positive into, negative out of specified terminal.

PACKAGE PIN OUT



RoHS/Pb-free 100% Matte Tin Lead finish

THERMAL DATA

LU Plastic MLPQ 16-Pin

THERMAL RESISTANCE-JUNCTION TO CASE, θ_{JC}	10 C/W
THERMAL RESISTANCE-JUNCTION TO AMBIENT, θ_{JA}	50 C/W

Junction Temperature Calculation: $T_J = T_A + (P_D \times \theta_{JA})$.

The θ_{JA} numbers are guidelines for the thermal performance of the device/pc-board system. All of the above assume no ambient airflow.



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Thank you for your interest in Microsemi® Analog Mixed Signal products.

The full data sheet for this device contains proprietary information.

To obtain a copy, please contact your local Microsemi sales representative. The name of your local representative can be obtained at the following link http://www.microsemi.com/contact/contactfind.asp

or

Contact us directly by sending an email to: IPGdatasheets@microsemi.com

Be sure to specify the data sheet you are requesting and include your company name and contact information and or voard.

We look forward to hearing from you.